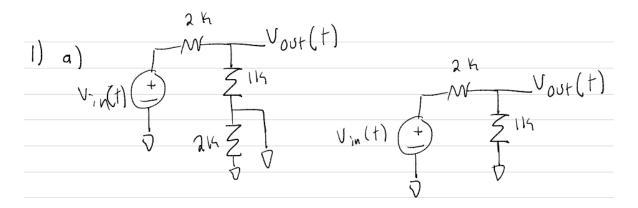
Homework 9 Solutions

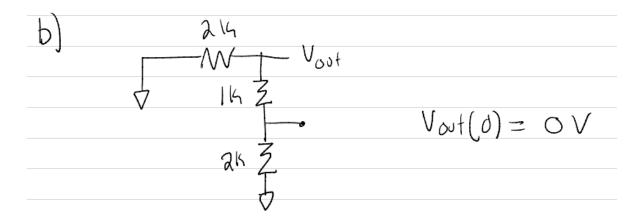
EE 330: FALL 2025

Problem 1

a)



b)



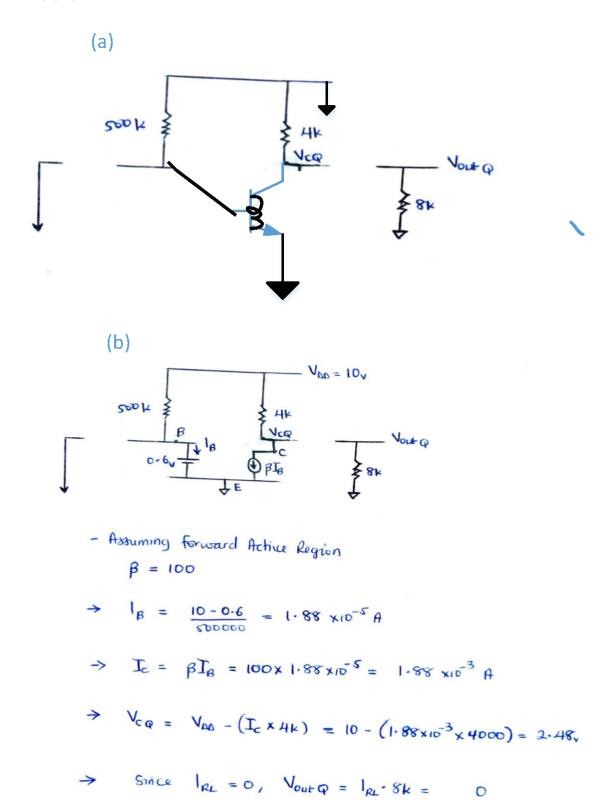
 $\mathbf{c})$

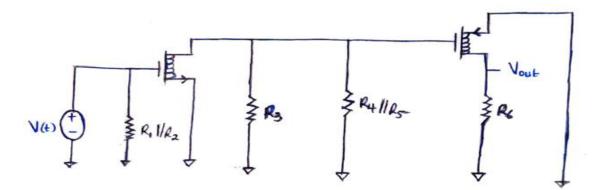
For small signal voltage gain:

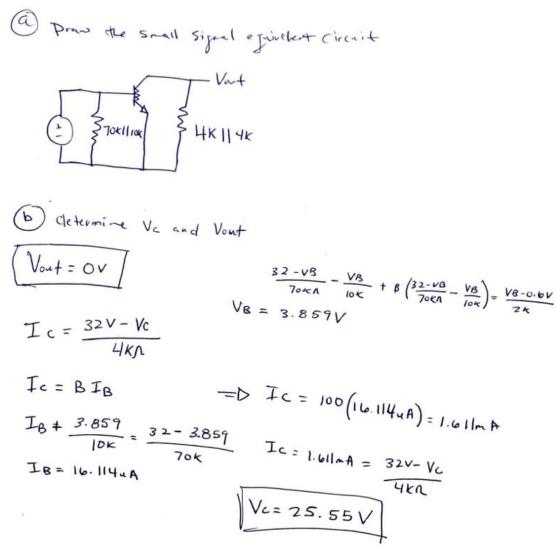
$$Av = \frac{1k}{1k + 2k} = \frac{\mathbf{1}}{\mathbf{3}}$$

d)

$$\begin{split} Vout(t) &= A_v \cdot V_{in}(t) = \frac{1}{3} \cdot (2sin(500t)) \\ \mathbf{Vout(t)} &= \frac{\mathbf{2}}{3} \sin(\mathbf{500t}) \end{split}$$







Alternately, if we assume I_B is negligible compared to the current through the 70K resistor, the voltage at the base is, by a voltage divider, (1/8)*32V = 4V. Thus, the emitter voltage is 4V - 0.6V = 3.4V. So the current in the emitter, $I_E = 3.4V/2K = 1.7mA$. But since β is large, $I_C = I_E$. Thus $V_C = 32V - I_C * 4K = 25.6V$.

Note this solution is somewhat simpler and the results are about the same as that obtained by including the base current.

a)

Assuming Saturation

$$V_{gs} = 0 - (-1) V = 1 V$$

$$V_{ds} = (2 - I_D \cdot 10k) - (-1) = 3 - I_D \cdot 10k$$

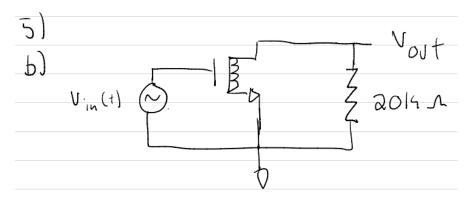
$$I_D = \mu_n C_{ox} \frac{W}{2 \cdot L} (V_{gs} - V_T)^2$$

$$100 \mu A = 250 \mu \frac{W}{2 \cdot 5\mu} (1 - 0.4)^2$$

$$W = \frac{100 \mu \cdot 10 \mu}{250 \mu \cdot 0.6^2}$$

$$W = 11.1 \mu m$$

b)



c)

Determine the small-signal voltage gain

$$Av = \frac{2I_{DQ}R}{V_{SS} + V_T} = \frac{2(100\mu)(10k)}{(-1) + 0.4}$$
$$Av = -3.33 \, V/V$$

d)

Determine the THD

$$THD = \frac{Vm}{4(V_{GS} - V_T)} = \frac{200 \, mV}{4(1 - 0.4)}$$

$$THD = 0.0833 = 8.33 \, \%$$

a)

Assuming the amplifier is ideal, $V_{IN} = V_N$

 $V_N = V_{DS}$ of the mosfet

VGS of Mosfet: $V_{GS} = V_G - V_S = 1 - 0 = 1 V$

For the Mosfet to be in saturation, $V_{DS} \ge V_{GS} - V_T$

Since $V_{DS} = V_C = V_{IN}$, thus $V_{DS} \le 10 \, mV$

The transistor is in the triode region; $V_{DS} < V_{GS} - V_T$

If $V_{xx} = 1 V$, the transistor can be represented as a resistor by the channel resistance.

$$R_{ch} = \frac{1}{\mu C_{ox} \frac{W}{L} (V_{gs} - V_T)} = \frac{1}{250 \mu \frac{12\mu}{1\mu} (1 - 0.4)}$$
$$R_{ch} = 555 \Omega$$

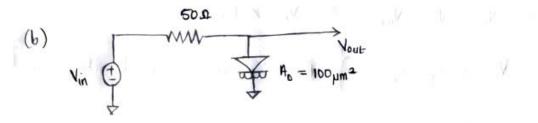
$$Av = 1 + \frac{R_F}{R_{ch}} = \mathbf{1} + \frac{\mathbf{R_F}}{\mathbf{555}\,\mathbf{\Omega}}\,\mathbf{V/V}$$

b)

From the R_{ch} equation, we notice that as V_{gs} increases, R_{ch} decreases; therefore, the gain of the non-inverting amplifier increases

Problem 7

(9) No DC current goes through the capacitor $\Rightarrow I_0 = I_B = J_S A(e^{\frac{V_L}{V_L}} - 1)$ $\Rightarrow V_D = V_L \ln\left(\frac{I_B}{J_S A} + 1\right) = 0.026 \ln\left(\frac{1 \times 10^{-3}}{10^{-14} \times 10^{16}} + 1\right) = 0.539 \text{ V}$



(c)
$$\frac{\left(V_{\text{out}} - V_{\text{in}}\right)}{50} + \frac{V_{\text{out}}}{R_0} = 0$$

$$\Rightarrow V_{\text{out}} \left(\frac{1}{50} + \frac{1}{R_0}\right) = \frac{V_{\text{in}}}{50}$$

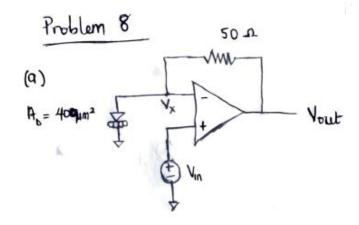
$$\Rightarrow \frac{V_{\text{out}}}{V_{\text{in}}} = \frac{1}{50} \left(\frac{1}{50} + \frac{1}{R_0}\right) = \frac{1}{1 + \frac{50}{R_0}}$$

Fut
$$R_0 = \frac{V_t}{I_{diods}} = \frac{0.026}{0.001} = 26\Omega$$

$$\Rightarrow \frac{V_{\text{out}}}{V_{\text{in}}} = \frac{1}{1 + \frac{50}{26}} = 0.342$$

(d)
$$R_0 = \frac{0.021}{0.005} = 5.2 \Omega$$

$$\frac{V_{\text{out}}}{V_{\text{in}}} = \frac{1}{1 + \frac{50}{5.2}} = 0.0942$$



(b) From the small signal equivalent circuit,
$$\frac{(V_X - V_{out})}{50} + \frac{V_X}{R_0} = 0$$

Assuming the amplifier is ideal, $V_x = V_{in}$

$$\rightarrow$$
 $V_{in}\left(\frac{1}{10} + \frac{1}{100}\right) = \frac{\sqrt{000}}{500}$

$$\rightarrow \frac{V_{out}}{V_{in}} = 1 + \frac{So}{\rho_{\Delta}}$$

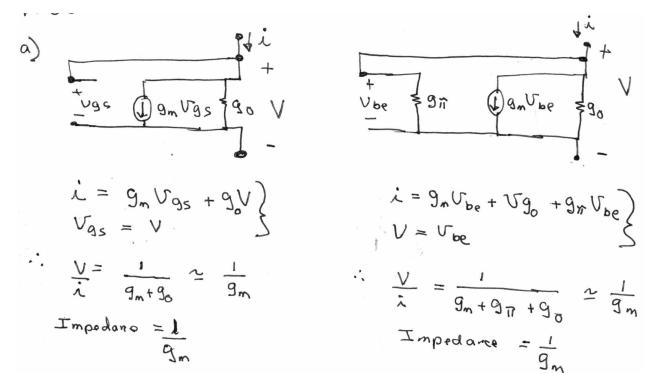
$$R_b = \frac{V_t}{1_{mA}} = \frac{0.626}{0.001} = 26 \Omega$$

$$\Rightarrow \frac{V_{\text{out}}}{V_{\text{in}}} = 1 + \frac{50}{26} = 2.923$$

(c)
$$\frac{\Lambda^{in}}{\Lambda^{ont}} = 1 + \frac{\delta^{in}}{20}$$

$$\ell_b = \frac{0.026}{10 \times 10^{-3}} = 2.6$$

$$\Rightarrow \frac{V_{out}}{V_{in}} = 1 + \frac{50}{2-6} = 20.23$$



b) small signal for both are resistors of value 1

c)

$$\begin{split} R_{eq} &= \frac{1}{\sqrt{\mu C_{ox} \frac{W}{L}} \sqrt{2I_D}} \\ R_{eq} &= \frac{1}{\frac{I_{DQ}}{\sqrt{250\mu} \sqrt{2 \cdot 1m}}} = 1.4 \ k\Omega \end{split} \qquad \qquad R_{eq} = \frac{25m}{1m} = 25 \ \Omega \end{split}$$

Problem 10

 $\mathbf{a})$

Must have $V_{DS} \ge V_{GS} - V_T$

$$2 V - I_D \cdot R_1 > (1 - 0.4) V$$

$$I_D = \mu_n C_{ox} \frac{W}{2 \cdot L} (V_{gs} - V_T)^2$$

$$I_D = 250 \mu \frac{18\mu}{2 \cdot 2\mu} (1 - 0.4)^2 = 405 \mu A$$

$$R_1 < \frac{2 V - 0.6 V}{I_D}$$

$$\mathbf{R}_1 < \mathbf{3.46 k\Omega}$$

$$Av = \mu_n C_{ox} \frac{W}{L} (V_{SS} + V_T) \cdot R$$

$$Av = 250 \mu \frac{18\mu}{2\mu} (-1 + 0.4) \cdot 1.15k$$

$$Av = -1.556 V/V$$

c)

$$V_{outQ} = V_{DD} - \mu_n C_{ox} \frac{W}{2L} (V_{SS} + V_T)^2 \cdot R$$

$$V_{outQ} = 2 - 250 \mu \frac{18\mu}{2 \cdot 2\mu} (-1 + 0.4)^2 \cdot 1.15k$$

$$V_{outQ} = 1.533 V$$

$$V_{out}(t) = V_{outQ} + Av \cdot V_m sin(\omega t)$$

$$V_{out}(t) = 1.533 + (-1.556) \cdot (1m \cdot sin(5000t + 75^\circ))$$

$$V_{out}(t) = 1.533 - 1.556m \cdot sin(5000t + 75^\circ)) V$$